

SHARP

OPTO-ELECTRONIC DEVICES DIVISION ELECTRONIC COMPONENTS GROUP SHARP CORPORATION

SPECIFICATION

| / DEV | ICE SPECIFI | CATION FO |)R | | | |) | | |
|-----------------|-------------|-----------|-------------|---------------------------------------|---------------|------|---|---|--|
| MOI | DEL No. | PHOTO | INTERRI | UPTER | | | | | |
| | | GP1 | S58VJ0 | 00F | | | | | |
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Product name: PHOTOINTERRUPTER

Model No.: GP1S58VJ000F

| 1. | These specification sheets include materials protected under copyright of Sharp Corporation ("Sharp") |
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2. When using this product, please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets, as well as the precautions mentioned below. Sharp assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets, and the precautions mentioned below.

(Precautions)

- (1) This product is designed for use in the following application areas;
 - · OA equipment · Audio visual equipment · Home appliances
 - Telecommunication equipment (Terminal) Measuring equipment
 - Tooling machines Computers

If the use of the product in the above application areas is for equipment listed in paragraphs (2) or (3), please be sure to observe the precautions given in those respective paragraphs.

- (2) Appropriate measures, such as fail-safe design and redundant design considering the safety design of the overall system and equipment, should be taken to ensure reliability and safety when this product is used for equipment which demands high reliability and safety in function and precision, such as;
 - · Transportation control and safety equipment (aircraft, train, automobile etc.)
 - Traffic signals Gas leakage sensor breakers Rescue and security equipment
 - · Other safety equipment
- (3) Please do not use this product for equipment which require extremely high reliability and safety in function and precision, such as;
 - Space equipment Telecommunication equipment (for trunk lines)
 - Nuclear power control equipment Medical equipment
- (4) Please contact and consult with a Sharp sales representative if there are any questions regarding interpretation of the above three paragraphs.
- 3. Please contact and consult with a Sharp sales representative for any questions about this product.

1. Application

This specification applies to the outline and characteristics of transmissive type photointerrupter, Model No. GP1S58VJ000F.

2. Outline

Refer to the attached drawing No. CY12512i02.

3. Ratings and characteristics

Refer to the attached sheet. Page 4 to 5.

4. Reliability

Refer to the attached sheet, Page 6.

5. Outgoing inspection Refer to the attached sheet, Page 7.

6. Supplements

6.1 Parts

Refer to the attached sheet, Page 8.

6.2 ODS materials

This product shall not contain the following materials.

Also, the following materials shall not be used in the production processfor this product.

Materials for ODS : CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Brominated flame retardants 6.3

Specific brominated flame retardants such as the PBBOs and PBBs are not used in this device at all.

6.4 Use of LEAD(Pb)

This product does not contain LEAD(Pb) more than RoHS restriction level.

6.5 Product mass: Approx. 0.50g

Country of origin: Japan, Indonesia, Philippine

7. Notes

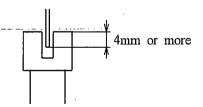
7.1 Circuit design

In circuit designing, make allowance for the degradation of the light emitting diode output that results from long continuous operation. (50% degradation/5 years)

7.2 Position of opaque board

Opaque board shall be installed at place 4mm or more from the top of elements.

(Example)



7.3 Soldering

To solder onto lead pins, solder at the position of 1.6mm or more from the package's bottom at 260°C for 5s or less. Please take care not to let any external force exert on lead pins when soldering or just after soldering. Please don't do soldering with preheating, and please don't do soldering by reflow.

Cleaning conditions:

Solvent cleaning: Solvent temperature 45°C or less

Immersion 3 min. or less

The effect to device by ultrasonic cleaning differs by cleaning bath size, Ultrasonic cleaning:

> ultrasonic power output, cleaning time, PCB size or device mounting condition etc. Please test it in actual using condition and confirm that doesn't occur any defect

before starting the ultrasonic cleaning.

Ethyl alcohol, Methyl alcohol, Isopropyl alcohol (3) Applicable solvent:

7.5 Flux

Some flux, which is used in soldering, may crack the package due to synergistic effect of alcohol in flux and the rise in temperature by heat in soldering. Therefore, in using flux, please make sure that it does not have any influence on appearance and reliability of the photointerrupter.



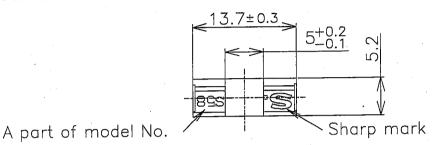
2. Outline (Drawing No.: CY12512i02)

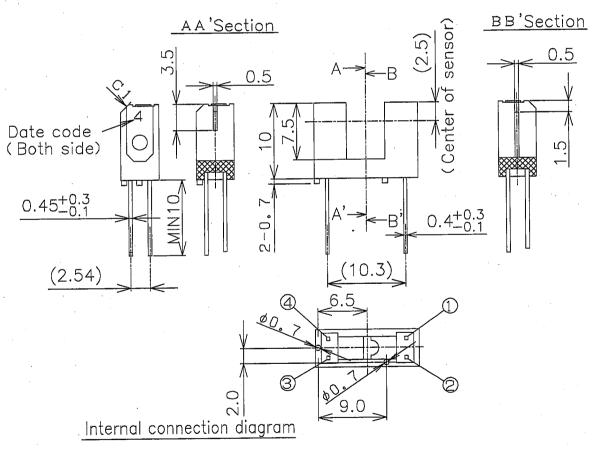
1) Unspecified tolerances shall be followed the list below.

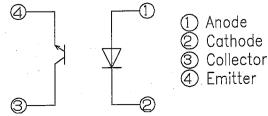
| Dimension | Tolerance(±) |
|------------|--------------|
| d ≤ 6 | 0.1 |
| 6 < d ≤ 18 | 0.2 |

2) Dimensions in parenthesis are shown for reference.

Scale: 2/1 Unit:1/1mm









3. Ratings and characteristics

3.1 Absolute maximum ratings

Ta=25℃

| | Parameter | Symbol | Rating | Unit |
|--------|--------------------------------|------------------|-------------|------------|
| | *I Forward current | I_{F} | 50 | mA |
| _ | *1,2 Peak forward current | I_{FM} | 1 | A |
| Input | Reverse voltage | V _R | 6 | V |
| | Power dissipation | Р | 75 | mW |
| | Collector-emitter voltage | V _{CEO} | 35 | V |
| | Emitter-collector voltage | V_{ECO} | 6 | V |
| Output | Collector current | Ic | 20 | mA |
| | *1 Collector power dissipation | Pc | 75 | mW |
| | Operating temperature | Topr | -25 to +85 | $^{\circ}$ |
| | Storage temperature | Tstg | -40 to +100 | °C |
| *3 | Soldering temperature | Tsol | 260 | $^{\circ}$ |

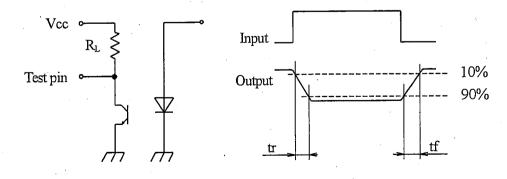
- *1 The derating factors of absolute maximum ratings due to ambient temperature are shown in Fig. 1, 2, 3.
- *2 Pulse width $\leq 100 \,\mu$ s, Duty ratio: 0.01
- *3 For 5s

3.2 Electro-optical characteristics

Ta=25℃

| | Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---------------------|--------------------------------------|-----------------------|---|------|------|------|------|
| | Forward voltage | $V_{\rm F}$ | I _F =20mA | - | 1.25 | 1.4 | V |
| Input | Peak forward voltage | V_{FM} | I _{FM} =0.5A | - | 3 | 4 | V |
| - | Reverse current | I_R | V _R =3V | - | - | 10 | μΑ |
| Output | Dark current | I_{CEO} | V _{CE} =20V | - | 1 | 100 | nA |
| | Collector current | Ic | V _{CE} =5V, I _F =20mA | 0.5 | - | 15.0 | mA |
| Transfer character- | Collector-emitter saturation voltage | V _{CE} (sat) | I _F =40mA, Ic=0.2mA | | _ | 0.4 | V |
| istics | Response time (Rise) | tr | V _{CE} =2V, Ic=2mA | - | 3 | 15 | μs |
| | Response time (Fall) | tf | $R_L=100\Omega$ | - | 4 | 20 | μs |

(Test circuit for response time)



#D-04GISSA GRUSS 8V 1000F

Fig.1 Forward current vs. ambient temperature

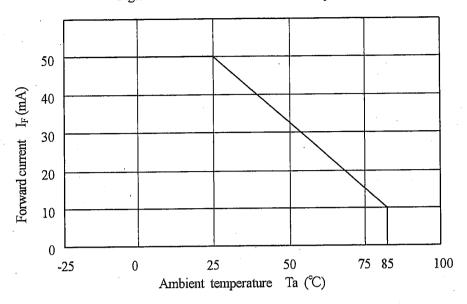


Fig.2 Collector power dissipation vs. ambient temperature

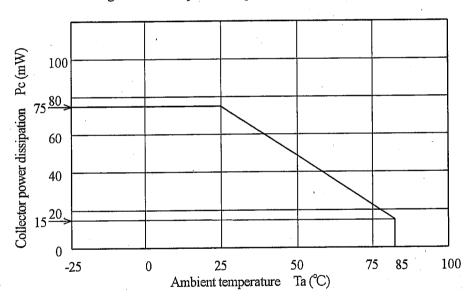
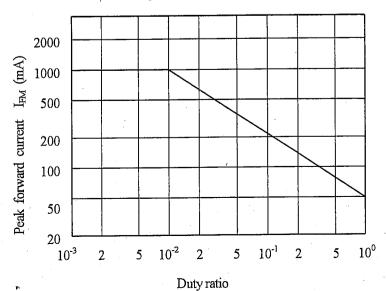


Fig.3 Peak forward current vs. duty ratio



(Pulse width $\leq 100 \,\mu$ s Ta=25°C)



4. Reliability

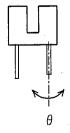
The reliability of products shall be satisfied with items listed below.

Confidence level: 90%

LTPD: 10 or 20

| Test Items | Test Conditions | Failure Judgement Criteria | Samples (n) Defective (c) |
|--------------------------------------|--|---|---------------------------|
| Temperature cycling | 1 cycle -40°C to +100°C (30min.) (30min.) 20 cycle test | | n=22, c=0 |
| High temp. and high humidity storage | +60°C, 90%RH, 500h | | n=22, c=0 |
| High temp. storage | +100°C, 500h | | n=22, c=0 |
| Low temp. storage | -40°C, 500h | $V_F \leq U \times 1.2$ $I_R \geq U \times 2$ | n=22, c=0 |
| Operation life | I _F =20mA, Ta=25°C, 500h | Ic≦L×0.8 | n=22, c=0 |
| Mechanical shock | 15000m/s², 0.5ms 3times/±X, ±Y, ±Z direction | I _{CEO} ≧U×2 | n=11, c=0 |
| Variable frequency vibration | 100 to 2000 to 100Hz/20min. 2h/X, Y, Z direction 100m/s ² | | n=11, c=0 |
| Terminal strength (Tension) | Weight: 10N 30s/each terminal | U: Upper specification limit | n=11, c=0 |
| Terminal strength (Bending) *1 | Weight: $5N$ $0^{\circ} \rightarrow 90^{\circ} \rightarrow 0^{\circ} \rightarrow -90^{\circ} \rightarrow 0^{\circ}$ 1 time bending | L: Lower specification limit | n=11, c=0 |
| Soldering heat | 260°C, 5 s, 1 time | | n=11, c=0 |
| Solderability *2 | 245°C, 5 s | Judgement only appearance Solder shall adhere at less than 95% area of immersed portion of lead. | n=11, c=0 |

*1 Terminal bending direction is shown below.



*2 The alloy composition of solder used should be Sn-3.0Ag-0.5Cu.
Flux used for precleaning should be equivalent to EC-19S(TAMURA KAKEN CORPORATION).



5. Outgoing inspection

5.1 Inspection items

(1) Electro-optical characteristics * $V_{F},V_{FM},I_{R},BV_{CEO},BV_{ECO},I_{CEO},Ic,V_{CE(sat)}$

(2) Appearance

5.2 Sampling method and Inspection levelA single sampling plan, normal inspection based on ISO 2859 is applied.

| Defect | Inspection item | Inspection level | AQL(%) |
|--------------|---|------------------|--------|
| Major defect | Characteristics defect Unreadable marking | П | 0.065 |
| Minor defect | Appearance defect except the above mentioned. | II | 0.25 |

ED-04G153A, GP1S58V100DF A March 1, 2005

6. Supplements

6.1 Parts

This product uses the below parts.

6.1.1 Light detector (PT480, Quantity: 1)

| Туре | Material | Maximum sensitivity wavelength (nm) | Sensitivity wavelength (nm) | Response time (μs) |
|-----------------|-----------------|-------------------------------------|--------------------------------|-----------------------|
| Phototransistor | Silicon (Si) | 800 | 400 to 1200 | 3 |

6.1.2 Light emitter (GL480, Quantity: 1)

| Туре | Material | Maximum light emitting wavelength (nm) | I/O Frequency (MHz) |
|--|----------|--|------------------------|
| Infrared light emitting diode (non-coherent) | GaAs | 950 | 0,3 |

6.1.3 Material

| Case | Lead flame finish |
|-------------------|-----------------------------|
| Black NORYL resin | Solder dip (Sn-3.0Ag-0.5Cu) |

6.1.4 Others

This product shall not be proof against radiation flux.